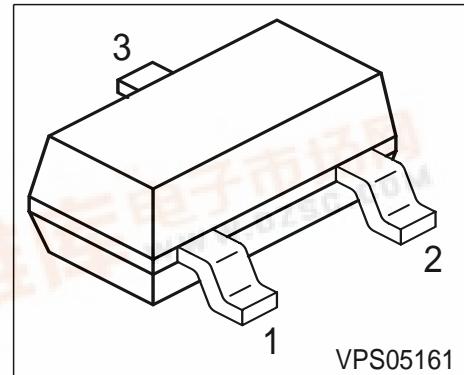




PNP Silicon High-Voltage Transistors

- Suitable for video output stages in TV sets and switching power supplies
- High breakdown voltage
- Low collector-emitter saturation voltage
- Complementary types: BFN24, BFN26 (NPN)



| Type | Marking | Pin Configuration | | | Package |
|-------|---------|-------------------|-------|-------|---------|
| BFN25 | FKs | 1 = B | 2 = E | 3 = C | SOT23 |
| BFN27 | FLs | 1 = B | 2 = E | 3 = C | SOT23 |

Maximum Ratings

| Parameter | Symbol | BFN25 | BFN27 | Unit | |
|---|-----------|-------------|-------|------|--|
| Collector-emitter voltage | V_{CEO} | 250 | 300 | V | |
| Collector-base voltage | V_{CBO} | 250 | 300 | | |
| Emitter-base voltage | V_{EBO} | 5 | 5 | | |
| DC collector current | I_C | 200 | | mA | |
| Peak collector current | I_{CM} | 500 | | | |
| Base current | I_B | 100 | | | |
| Peak base current | I_{BM} | 200 | | | |
| Total power dissipation, $T_S = 74^\circ\text{C}$ | P_{tot} | 360 | | mW | |
| Junction temperature | T_j | 150 | | | |
| Storage temperature | T_{stg} | -65 ... 150 | | | |

Thermal Resistance

| | | | |
|--|------------|------------|-----|
| Junction - soldering point ¹⁾ | R_{thJS} | ≤ 210 | K/W |
|--|------------|------------|-----|

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified.

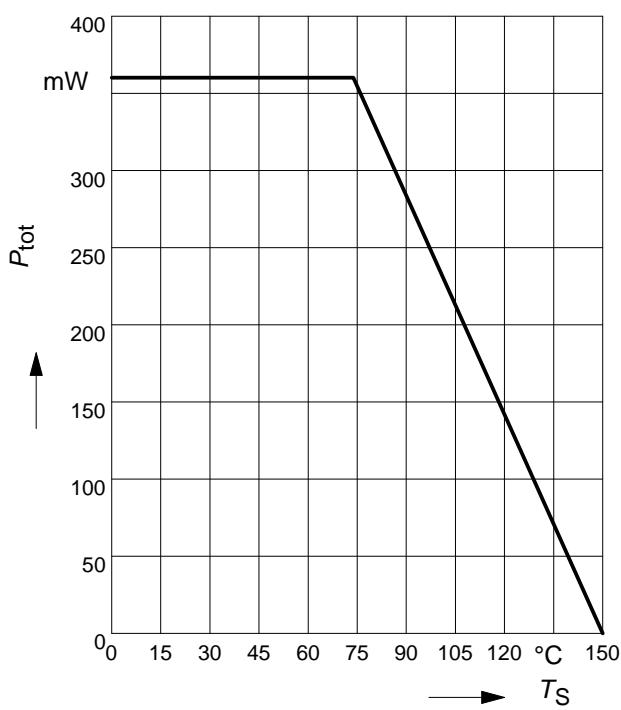
| Parameter | Symbol | Values | | | Unit |
|--|-----------------------------|--------|------|------|---------------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage $I_C = 1 \text{ mA}, I_B = 0$ | $V_{(\text{BR})\text{CEO}}$ | 250 | - | - | V |
| | BFN25 | 300 | - | - | |
| | BFN27 | | | | |
| Collector-base breakdown voltage $I_C = 100 \mu\text{A}, I_E = 0$ | $V_{(\text{BR})\text{CBO}}$ | 250 | - | - | |
| | BFN25 | 300 | - | - | |
| | BFN27 | | | | |
| Emitter-base breakdown voltage $I_E = 100 \mu\text{A}, I_C = 0$ | $V_{(\text{BR})\text{EBO}}$ | 5 | - | - | |
| Collector cutoff current $V_{CB} = 200 \text{ V}, I_E = 0$ | I_{CBO} | - | - | 100 | nA |
| $V_{CB} = 250 \text{ V}, I_E = 0$ | BFN25 | - | - | 100 | |
| | BFN27 | | | | |
| Collector cutoff current $V_{CB} = 200 \text{ V}, I_E = 0, T_A = 150^\circ\text{C}$ | I_{CBO} | - | - | 20 | μA |
| $V_{CB} = 250 \text{ V}, I_E = 0, T_A = 150^\circ\text{C}$ | BFN25 | - | - | 20 | |
| | BFN27 | | | | |
| Emitter cutoff current $V_{EB} = 3 \text{ V}, I_C = 0$ | I_{EBO} | - | - | 100 | nA |
| DC current gain 1) $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ | h_{FE} | 25 | - | - | - |
| $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ | | 40 | - | - | |
| $I_C = 30 \text{ mA}, V_{CE} = 10 \text{ V}$ | BFN25 | 40 | - | - | |
| | BFN27 | 30 | - | - | |
| Collector-emitter saturation voltage1) $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$ | V_{CEsat} | - | - | 0.4 | V |
| | BFN25 | - | - | 0.5 | |
| | BFN27 | | | | |
| Base-emitter saturation voltage 1) $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$ | V_{BEsat} | - | - | 0.9 | |

1) Pulse test: $t < 300\mu\text{s}; D < 2\%$

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified.

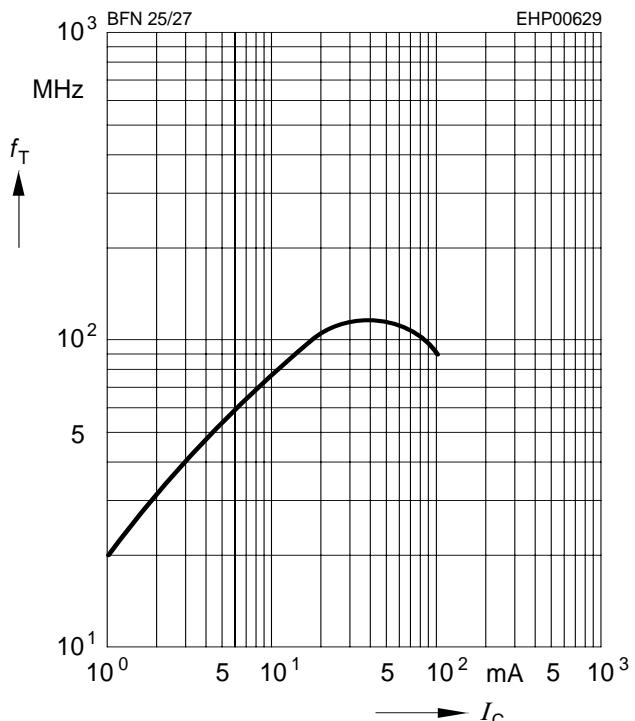
| Parameter | Symbol | Values | | | Unit |
|--|----------|--------|------|------|------|
| | | min. | typ. | max. | |
| AC Characteristics | | | | | |
| Transition frequency $I_C = 20 \text{ mA}, V_{CE} = 10 \text{ V}, f = 20 \text{ MHz}$ | f_T | - | 100 | - | MHz |
| Collector-base capacitance $V_{CB} = 30 \text{ V}, f = 1 \text{ MHz}$ | C_{cb} | - | 2.5 | - | pF |

Total power dissipation $P_{\text{tot}} = f(T_S)$



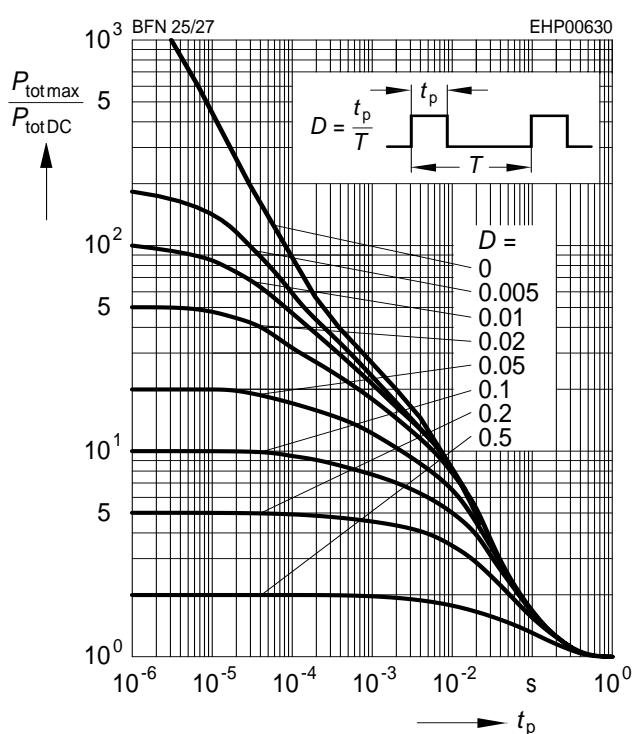
Transition frequency $f_T = f(I_C)$

$$V_{\text{CE}} = 10\text{V}$$



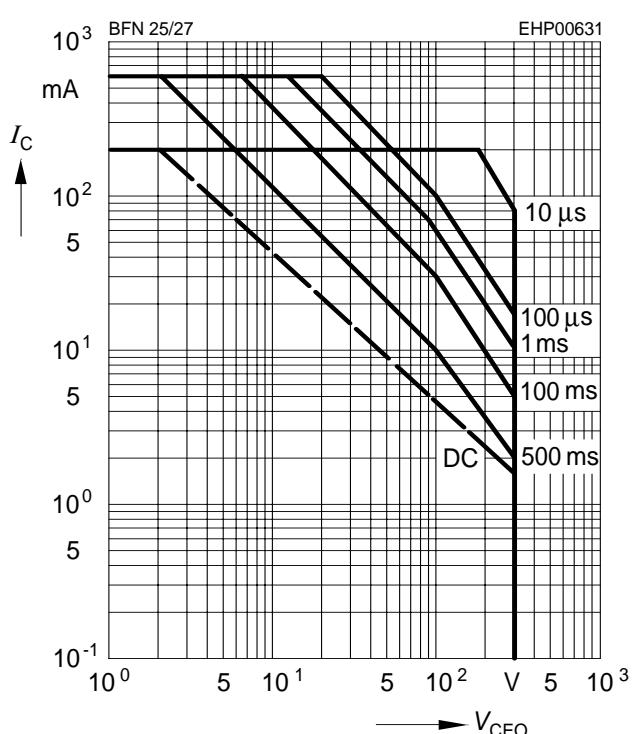
Permissible pulse load

$$P_{\text{totmax}} / P_{\text{totDC}} = f(t_p)$$

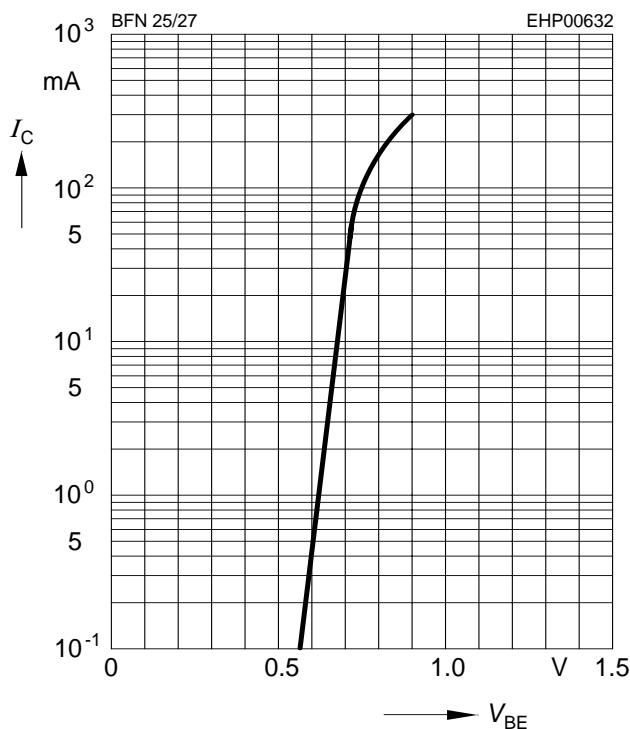


Operating range $I_C = f(V_{\text{CEO}})$

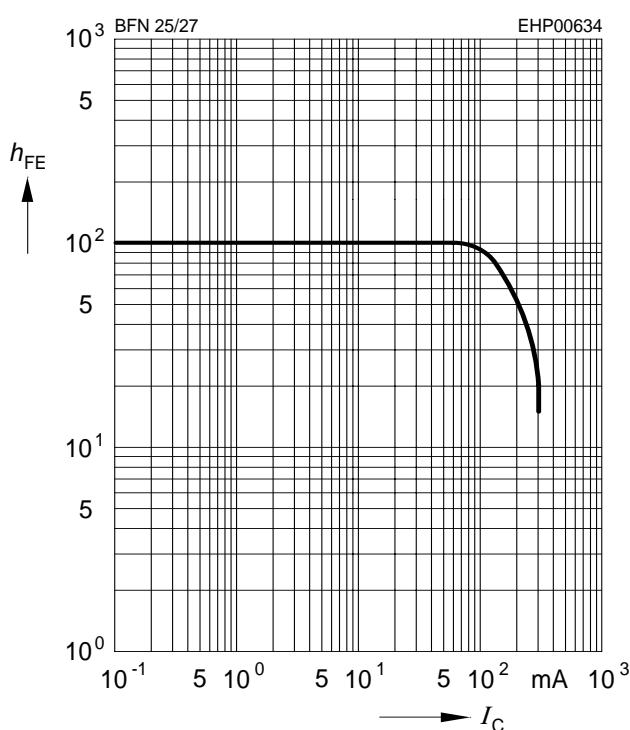
$$T_A = 25^\circ\text{C}, D = 0$$



Collector current $I_C = f(V_{BE})$
 $V_{CE} = 10 \text{ V}$



DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 10\text{V}$



Collector cutoff current $I_{CBO} = f(T_A)$
 $V_{CB} = 200\text{V}$

